NSN 5962-01-466-4493

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Next higher drawing is 400-17300/end item is aircraft, b-1b
Features Provided:
Monolithic and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Product Name:
Field programmable gate array, processor
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Memory Device Type:
Pal
Special Features:
Used with 5962-9550801mxa/bin speed 126.6 ns
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
207 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0